

# To Our Customers

Continuing it's rich tradition of partnering with high quality Japanese semiconductor suppliers, CEL is now partnering with THine from May of 2015 onwards.



# THC63LVDM83C(5S)

#### REDUCED SWING LVDS 24Bit COLOR HOST-LCD PANEL INTERFACE

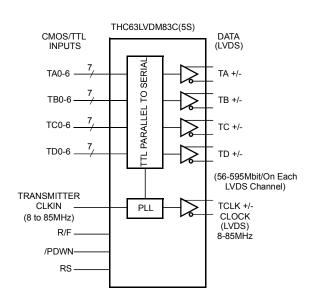
#### General Description

The THC63LVDM83C(5S) transmitter is designed to support pixel data transmission between Host and Flat Panel Display from NTSC up to SXGA+ resolutions. The THC63LVDM83C(5S) converts 28bits of CMOS/ TTL data into LVDS(Low Voltage Differential Signaling) data stream. The transmitter can be programmed for rising edge or falling edge clocks through a dedicated pin. At a transmit clock frequency of 85MHz, 24bits of RGB data and 4bits of timing and control data (HSYNC, VSYNC, CNTL1, CNTL2) are transmitted at an effective rate of 595Mbps per LVDS channel.

#### Features

- Wide dot clock range: 8-85MHz suited for NTSC, VGA, SVGA, XGA
- PLL requires no external components
- Supports spread spectrum clock generator
- On chip jitter filtering
- Clock edge selectable
- Supports reduced swing LVDS for low EMI
- Power down mode
- Low power single 3.3V CMOS design
- Low profile 56 Lead TSSOP Package
- 1.2 up to 3.3V tolerant data inputs to connect directly to low power, low voltage application and graphic processor.
- Backward compatible with THC63LVDM83R(24bits)

## Block Diagram



## Pin Out

THC	63LVDM83C(5	S)
123456789991112131456778928282878	•	56   TA4     55   TA3     54   TA2     53   GND     52   TA1     51   TA0     50   TD0     49   LVDS GND     48   TA-     47   TA+     46   TB-     44   LVDS GND     42   TC-     41   TC+     40   TCLK+     38   TD-     36   LVDS GND     35   PLL GND     35   PLL GND     34   PLL VCC     33   TC6     30   TC6     29   GND

2/12





# Pin Description

Pin Name	Pin #	Туре	Description				
TA+, TA-	47, 48	LVDS OUT					
TB+, TB-	45, 46	LVDS OUT					
TC+, TC-	41, 42	LVDS OUT	LVDS Data Out.				
TD+, TD-	37, 38	LVDS OUT					
TCLK+, TCLK-	39, 40	LVDS OUT	LVDS Clock Out.				
TA0 ~ TA6	51, 52, 54, 55, 56, 3, 4	IN					
TB0 ~ TB6	6, 7, 11, 12, 14, 15, 19	IN	Bivel Deta Innuta				
TC0 ~ TC6	20, 22, 23, 24, 27, 28, 30	IN	Pixel Data Inputs.				
TD0 ~ TD6	50, 2, 8, 10, 16, 18, 25	IN					
/PDWN	32	IN	H: Normal operation,				
POWN	52	IIN	L: Power down (all outputs are Hi-Z)				
RS	1	IN	LVDS swing mode, VREF select.   RS LVDS Small Swing   Swing Input Support   VCC 350mV N/A   0.6 ~ 1.4V 350mV RS=VREF <sup>a</sup> GND 200mV N/A   a. VREF is Input Reference Voltage.				
R/F	17	IN	Input Clock Triggering Edge Select. H: Rising edge, L: Falling edge				
VCC	9, 26	Power	Power Supply Pins for TTL inputs and digital circuitry.				
CLKIN	31	IN	Clock in.				
GND	5, 13, 21, 29, 53	Ground	Ground Pins for TTL inputs and digital circuitry.				
LVDS VCC	44	Power	Power Supply Pins for LVDS Outputs.				
LVDS GND	36, 43, 49	Ground	Ground Pins for LVDS Outputs.				
PLL VCC	34	Power	Power Supply Pin for PLL circuitry.				
PLL GND	33, 35	Ground	Ground Pins for PLL circuitry.				



# Absolute Maximum Ratings<sup>1</sup>

Supply Voltage (V <sub>CC</sub> )	-0.3V ~ +4.0V
CMOS/TTL Input Voltage	-0.3V ~ (V <sub>CC</sub> + 0.3V)
CMOS/TTL Output Voltage	-0.3V ~ (V <sub>CC</sub> + 0.3V)
LVDS Driver Output Voltage	-0.3V ~ (V <sub>CC</sub> + 0.3V)
Output Current	continuous
Junction Temperature	+125°C
Storage Temperature Range	-55°C ~ +150°C
Resistance to soldering heat	+260°C/10sec
Maximum Power Dissipation @+25 °C	0.5W

### Recommended Operating Conditions

Parameter	Min	Тур	Max	Units
All Supply Voltage	3.0	3.3	3.6	V
Operating Ambient Temperature	-40		85	°C
CLK IN Frequency	8		85	MHz

<sup>1. &</sup>quot;Absolute Maximum Ratings" are those valued beyond which the safety of the device can not be guaranteed. They are not meant to imply that the device should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.



#### **Electrical Characteristics**

CMOS/TTL DC Specifications
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Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V <sub>IH</sub>	High Level Input Voltage	RS=VCC or GND	2.0		V <sub>CC</sub>	V
V <sub>IL</sub>	Low Level Input Voltage	RS=VCC or GND	GND		0.8	V
V <sub>DDQ</sub> <sup>1</sup>	Small Swing Voltage		1.2		2.8	V
V <sub>REF</sub>	Input Reference Voltage	Small Swing (RS=V <sub>DDQ</sub> /2)		V <sub>DDQ</sub> /2		
$V_{SH}^2$	Small Swing High Level Input Voltage	$V_{REF} = V_{DDQ}/2$	V <sub>DDQ</sub> /2 +100mV			V
$V_{SL}^2$	Small Swing Low Level Input Voltage	$V_{REF} = V_{DDQ}/2$			V <sub>DDQ</sub> /2 -100mV	V
I <sub>INC</sub>	Input Current	$0V \le V_{IN} \le V_{CC}$			±10	uA

 $V_{CC} = VCC = PLL VCC = LVDS VCC$ 

Notes:  ${}^{1}V_{DDQ}$  voltage defines max voltage of small swing input. It is not an actual input voltage.  ${}^{2}$  Small swing signal is applied to TA0-6,TB0-6,TC0-6,TD0-6 and CLKIN.

#### LVDS Transmitter DC Specifications

V<sub>CC</sub> = VCC = PLL VCC = LVDS VCC

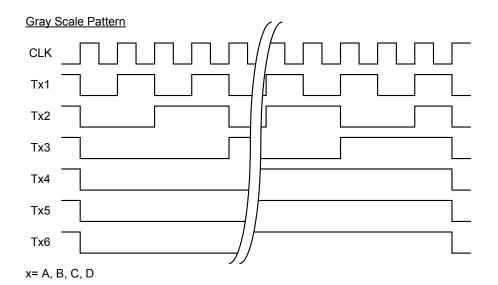
Symbol	Parameter	Cond	itions	Min.	Тур.	Max.	Units
VOD Differential Output Voltage F	Differential Output Valtage	RL=100 Ω	Normal swing RS=V <sub>CC</sub>	250	350	500	mV
	RL-100 22	Reduced swing RS=GND	100	200	300	mV	
ΔVOD	Change in VOD between complementary output states	RL=100 Ω				35	mV
VOC	Common Mode Voltage			1.125	1.25	1.375	V
ΔVOC	Change in VOC between complementary output states					35	mV
I <sub>OS</sub>	Output Short Circuit Current	VOUT=0V, RL=100 Ω				-24	mA
I <sub>OZ</sub>	Output TRI-STATE Current	/PDWN=0V, V <sub>OUT</sub> =0V to V <sub>CC</sub>				±10	uA



# Supply Current

 $V_{CC}$  = VCC = PLL VCC = LVDS VCC

Symbol	Parameter	Condition(*)		Тур.	Max.	Units
I <sub>TCCG</sub>	Transmitter Supply	RL=100 Ω ,CL=5pF	RS=V <sub>CC</sub>	52	58	mA
	Current	V <sub>CC</sub> =3.3V, f=85MHz	RS=GND	40	46	mA
	ounch	Gray Scale Pattern	NO-GND			IIIA
	Transmitter Supply	RL=100 Ω ,CL=5pF	RS=V <sub>CC</sub>	61	67	mA
I <sub>TCCW</sub>	Current	V <sub>CC</sub> =3.3V, f=85MHz Worst Case Pattern	RS=GND	50	56	mA
I <sub>TCCS</sub>	Transmitter Power Down Supply Current	/PDWN = L			10	uA



#### Worst Case Pattern

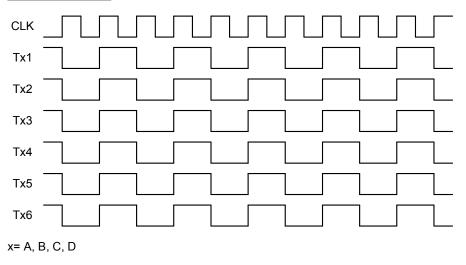


Fig1. Data Pattern



## Switching Characteristics

 $V_{CC}$  = VCC = PLL VCC = LVDS VCC

Symbol	Parameter	Min.	Тур.	Max.	Units
t <sub>TCIT</sub>	CLK IN Transition time			5.0	ns
t <sub>TCP</sub>	CLK IN Period	11.7	Т	125	ns
t <sub>TCH</sub>	CLK IN High Time	0.35T	0.5T	0.65T	ns
t <sub>TCL</sub>	CLK IN Low Time	0.35T	0.5T	0.65T	ns
t <sub>TCD</sub>	CLK IN to TCLK+/- Delay		3Т		ns
t <sub>TS</sub>	TTL Data Setup to CLK IN	2.5			ns
t <sub>TH</sub>	TTL Data Hold from CLK IN	0			ns
t <sub>LVT</sub>	LVDS Transition Time		0.6	1.5	ns
t <sub>TOP1</sub>	Output Data Position0 (T=11.7ns)	-0.2	0.0	+0.2	ns
t <sub>TOP0</sub>	Output Data Position1 (T=11.7ns)	$\frac{T}{7}$ – 0.2	$\frac{T}{7}$	$\frac{T}{7}$ + 0.2	ns
t <sub>TOP6</sub>	Output Data Position2 (T=11.7ns)	$2\frac{T}{7} - 0.2$	$2\frac{T}{7}$	$2\frac{T}{7} + 0.2$	ns
t <sub>TOP5</sub>	Output Data Position3(T=11.7ns)	$3\frac{T}{7} - 0.2$	$3\frac{T}{7}$	$3\frac{T}{7} + 0.2$	ns
t <sub>TOP4</sub>	Output Data Position4 (T=11.7ns)	$4\frac{T}{7} - 0.2$	$4\frac{T}{7}$	$4\frac{T}{7} + 0.2$	ns
t <sub>TOP3</sub>	Output Data Position5 (T=11.7ns)	$5\frac{T}{7} - 0.2$	5 <del>7</del>	$5\frac{T}{7} + 0.2$	ns
t <sub>TOP2</sub>	Output Data Position6 (T=11.7ns)	$6\frac{T}{7} - 0.2$	6 <del>7</del>	$6\frac{T}{7} + 0.2$	ns
t <sub>TPLL</sub>	Phase Lock Loop Set			10.0	ms

AC Timing Diagrams

TTL Input

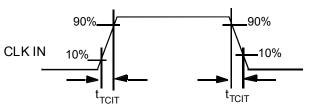


Fig2. CLKIN Transition Time

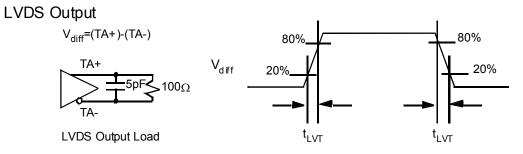
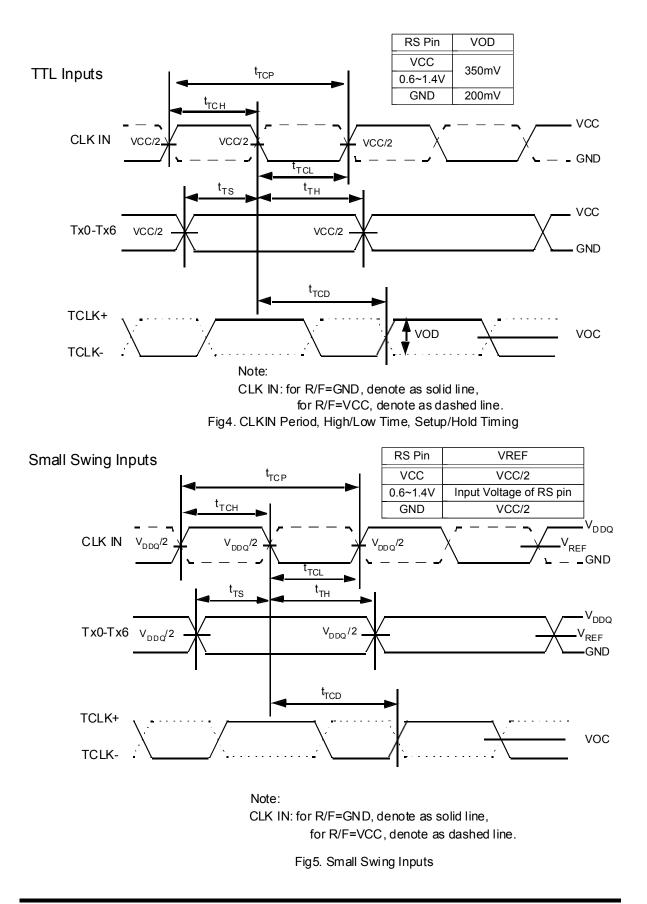


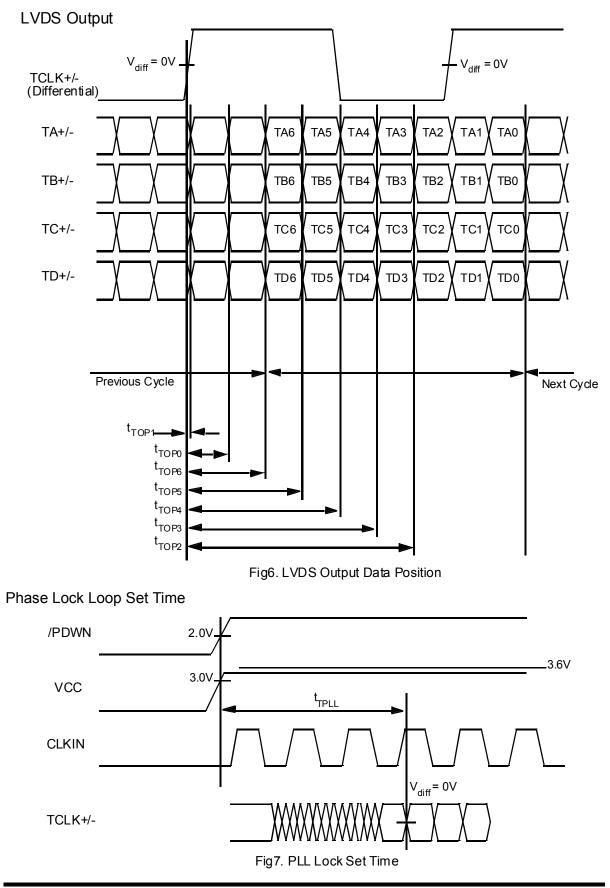
Fig3. LVDS Output Load and Transition Time







AC Timing Diagrams





#### Note

1)Cable Connection and Disconnection

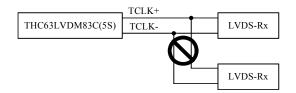
Don't connect and disconnect the LVDS cable, when the power is supplied to the system.

#### 2)GND Connection

Connect the each GND of the PCB which THC63LVDM83C(5S) and LVDS-Rx on it. It is better for EMI reduction to place GND cable as close to LVDS cable as possible.

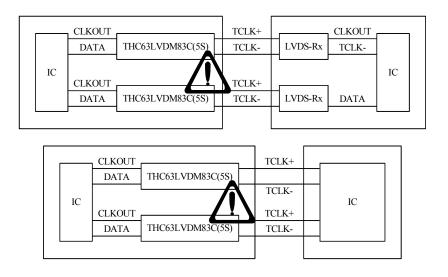
#### 3)Multi Drop Connection

Multi drop connection is not recommended.



#### 4)Asynchronous use

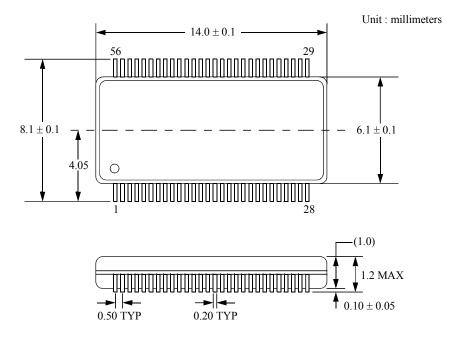
Asynchronous use such as following systems are not recommended.





# Package

56 Lead Molded Thin Shrink Small Outline Package, JEDEC





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- 1. The product specifications described in this material are subject to change without prior notice.
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- 7. Please note that this product is not designed to be radiation-proof.
- 8. Customers are asked, if required, to judge by themselves if this product falls under the category of strategic goods under the Foreign Exchange and Foreign Trade Control Law.

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